

PC9D10

**Ultra-high Speed Response,
2-channel OPIC Photocoupler**

■ Features

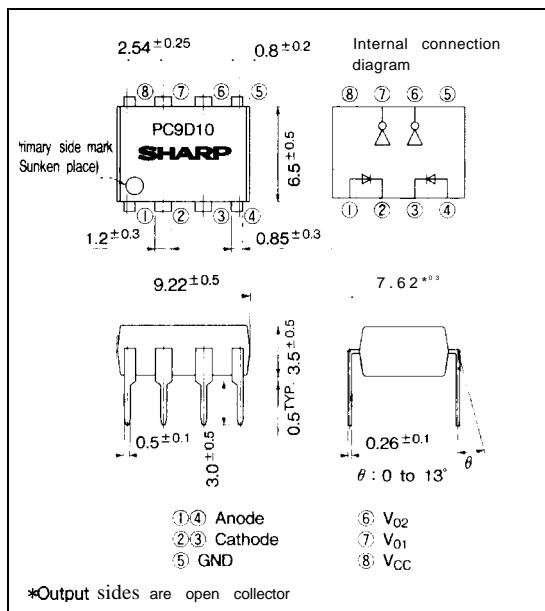
1. Built-in 2-channel
2. Ultra-high speed response
(t_{PHL}, t_{PLH} : TYP. 50ns at $R_L = 350\Omega$)
3. Isolation voltage between input and output
($V_{ISO} \geq 500V_{rms}$)
4. Low input current drive (I_{FLH} : MAX. 5mA)
5. Instantaneous common mode rejection voltage CM_H : TYP. 500V/ μ s
6. Recognized by UL file No. 64380

■ Applications

1. Computer peripherals high speed interface for microcomputer systems
2. High speed line receivers
3. Digital audio line equipment
4. Interface with various data transfer equipment

■ Outline Dimensions

(Unit : mm)



*Output sides are open collector

"OPIC" (Optical IC) is a trademark of the SHARP Corporation.
An OPIC consists of a light-detecting element and signal processing circuit integrated onto a single chip.

■ Absolute Maximum Ratings

(Ta = 25°C)

	Parameter	Symbol	Rating	Unit
Input	*1*2 Forward current	I _F	15	mA
	*2 Reverse voltage	V _R	5	v
	*1*2 Power dissipation	P	4(I)	mW
output	*1 Supply voltage	V _{CC}	7	v
	*2 High level output voltage	V _{OH}	7	v
	*2 Low level output current	I _{OL}	16	mA
	Collector power dissipation	P _C	60	mW
	4 Isolation voltage	V _{ISO}	2500	V _{rms}
	Operating temperature	T _{opr}	0 to +70	°C
	Storage temperature	T _{stg}	-55 to +125	°C
	*5 Soldering temperature	T _{sot}	260	°C

*1 Ta = 0 to 70°C

*2 Each channel

*3 Fnr 1 minute max.

*4 AC for 1 minute, 40 to 60%RH. Apply the specified voltage between the whole of the electrode pins on the input side and the whole of the electrode pins on the output side.

*5 2mm or more away from the lead base for 10 seconds or less

Electro-optical Characteristics(Unless otherwise specified, $T_a = 0$ to $+70^\circ\text{C}$)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX	Unit
Input	Forward voltage	V_F	$T_a = 25^\circ\text{C}, I_F = 10\text{mA}$	—	1.6	1.75	v
	Reverse current	I_R	$T_a = 25^\circ\text{C}, V_R = 5\text{V}$	—	—	10	μA
	Terminal capacitance	C_t	$T_a = 25^\circ\text{C}, V=0, f = 1\text{MHz}$	—	60	250	pF
output	High level output current	I_{OH}	$V_{CC} = V_O = 5.5\text{V}, I_F = 250\mu\text{A}$	—	2	250	μA
	Low level output voltage	V_{OL}	$V_{CC} = 5.5\text{V}, I_F = 5\text{mA}, I_{OL} = 13\text{mA}$	—	0.4	0.6	v
	High level supply current	I_{CH}	$V_{CC} = 5.5\text{V}, I_F = 0$	—	14	30	mA
	Low level supply current	I_{CL}	$V_{CC} = 5.5\text{V}, I_F = 10\text{mA}$	—	26	36	mA
Transfer characteristics	"High \rightarrow Low" threshold input current	I_{FHLL}	$V_{CC} = 5\text{V}, V_O = -0.8\text{V}, R_L = 350\Omega$	—	2.5	5	mA
	Isolation resistance	R_{ISO}	$T_a = 25^\circ\text{C}, DC 500\text{V}, 40 \text{ to } 60\% RH$	5×10^{10}	10^{11}	—	Ω
	Floating capacitance	C_f	$T_a = 25^\circ\text{C}, V=0, f = 1\text{MHz}$	—	0.6	—	pF
Response time	High \rightarrow Low propagation delay time	t_{PHL}	$T_a = 25^\circ\text{C}, V_{CC} = 5\text{V}$ Fig. 1	—	50	75	ns
	Low \rightarrow High propagation delay time	t_{PLH}	$R_L = 350\Omega, C_L = 15\text{pF}$	—	50	75	ns
	Rise time, Fall time	t_r, t_f	$I_F = 7.5\text{mA}$	—	30	60	ns
CMR	Instantaneous common mode rejection voltage "High level output"	CM_H	$T_a = 25^\circ\text{C}, V_{CC} = 5\text{V}, V_{OMIN} = -2\text{V}$ Fig. 2 $V_{CM} = 10\text{V}, R_L = 350\Omega, I_F = 0$	100	500	—	$\text{V}/\mu\text{s}$
	Instantaneous common mode rejection voltage "Low level output"	CM_L	$T_a = 25^\circ\text{C}, V_{CC} = 5\text{V}, V_{OMAX} = 0.8\text{V}$ Fig. 2 $V_{CM} = 10\text{V}, R_L = 350\Omega, I_F = 5\text{mA}$	-100	-500	—	$\text{V}/\mu\text{s}$

All typical values : at $T_a = 25^\circ\text{C}, V_{CC} = 5\text{V}$

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Recommended Operating Conditions

Parameter	Symbol	MIN.	MAX.	Unit
Low level input current	I_{FL}	0	250	μA
High level input current	I_{FH}	7	15	mA
Supply voltage	V_{CC}	4.5	5.5	v
Fanout (TTL load)	N	—	8	—
Operating temperature	T_{opr}	0	70	°c

Connect a ceramic by-pass capacitor (0.01 to 0.1 μF) between V_{CC} and GND at the position within 1cm from pin.

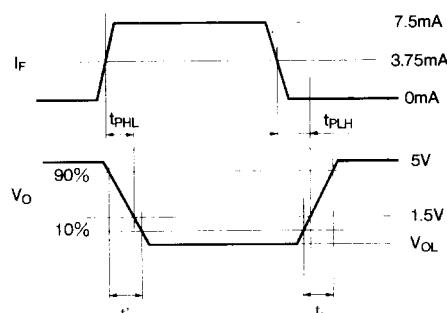
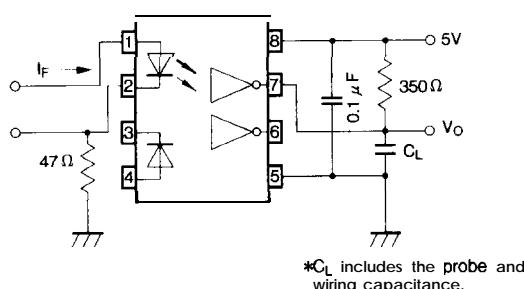
Fig. 1 Test Circuit for t_{PHL} , t_{PLH} , t_r and t_f 

Fig. 2 Test Circuit for CM_H and CM_L

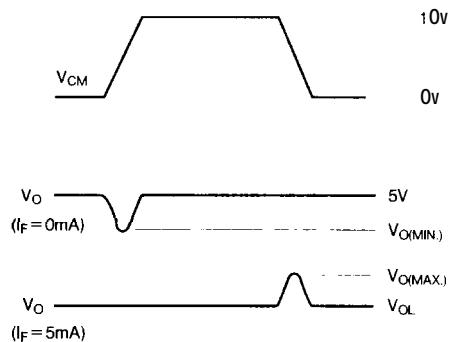
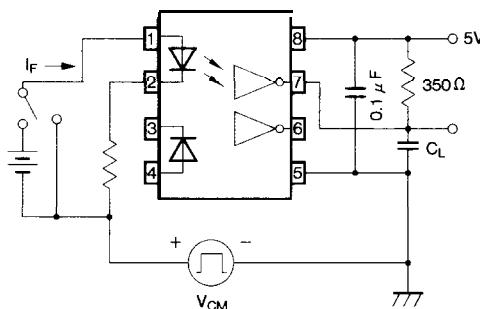


Fig. 3 Collector Power Dissipation vs. Ambient Temperature

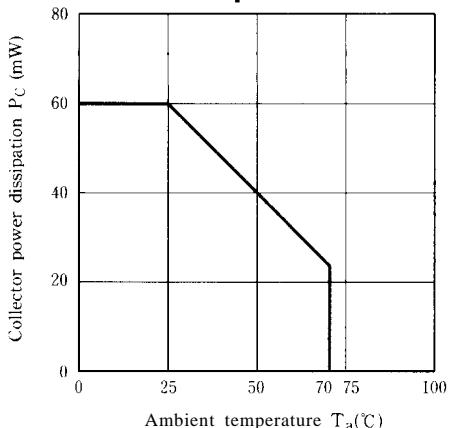


Fig. 5 High Level Output Current vs. Ambient Temperature

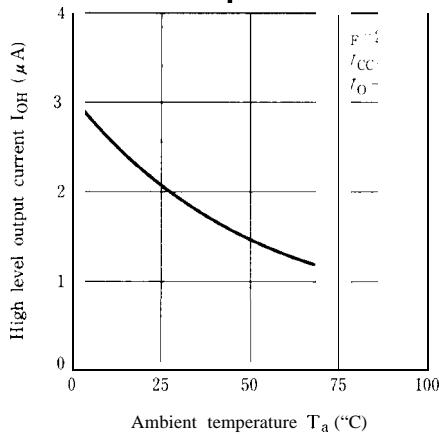
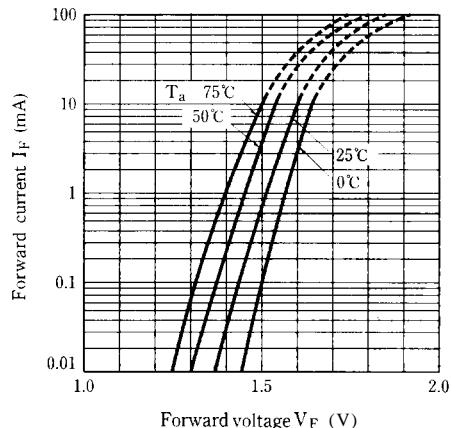


Fig. 4 Forward **Current** va. **Forward Voltage**



**Fig. 6 Low Level Output Voltage vs.
Ambient Temperature**

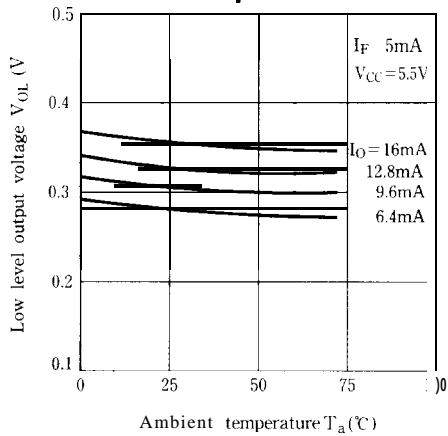
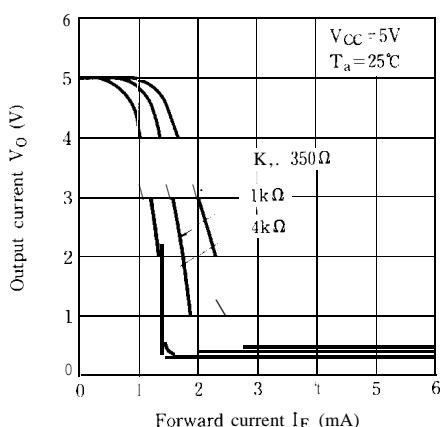
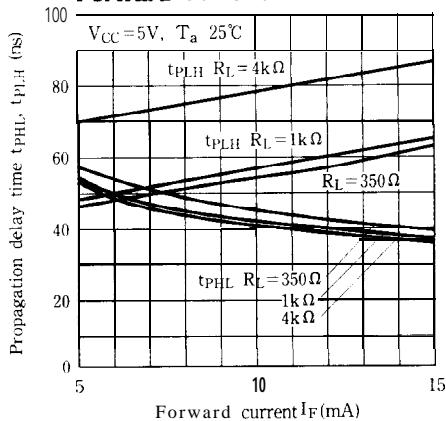
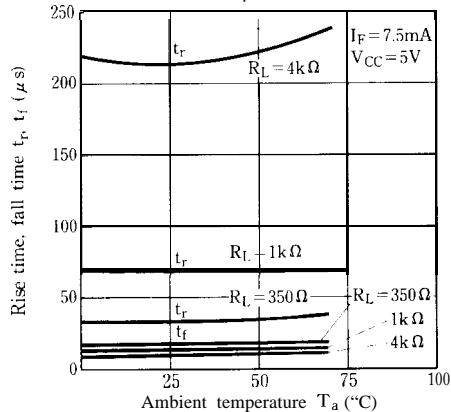
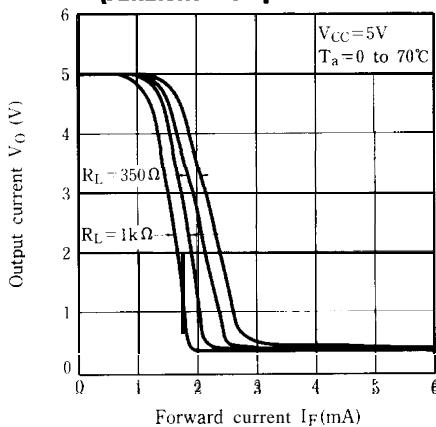
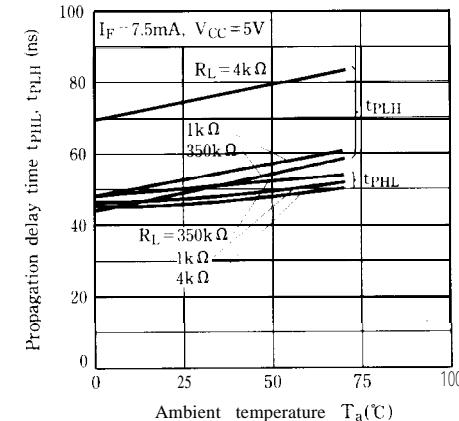


Fig. 7-a Output Voltage vs. Forward Current**Fig. 8 Propagation Delay Time vs. Forward Current****Fig. 10 Rise Time, Fall Time vs. Ambient Temperature****Fig. 7-b Output Voltage vs. Forward Current (Ambient Temp. Characteristics)****Fig. 9 Propagation Delay Time vs. Ambient Temperature**

■ Precautions for USE

- (1) Handle this product the same as with other integrated circuits against static electricity.
- (2) As for other general cautions, refer to the chapter "Precautions for Use" (Page 78 to 93).